

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

2SK3824

FEATURES

- Drain Current : I_D= 60A@ T_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage : V_{DSS}= 60V(Min)
- Static Drain-Source On-Resistance
- : $R_{DS(on)}$ = 15m Ω (Max) @V_{GS}=10V
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

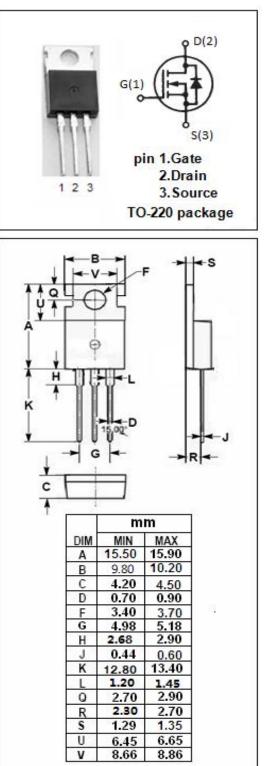
 motor drive, DC-DC converter, power switch and solenoid drive.

ABSOLUTE MAXIMUM KATINGS(Ta=23 C)						
PARAMETER VALUE		UNIT				
Drain-Source Voltage 60		V				
Gate-Source Voltage-Continuous ±20		V				
Drain Current-Continuous 60		A				
Drain Current-Single Pluse	240	A				
Total Dissipation @Tc=25℃	al Dissipation @T _c =25°C 60					
Max. Operating Junction Temperature	-55~150	°C				
Storage Temperature	-55~150	°C				
	PARAMETER Drain-Source Voltage Gate-Source Voltage-Continuous Drain Current-Continuous Drain Current-Single Pluse Total Dissipation @Tc=25°C Max. Operating Junction Temperature	PARAMETERVALUEDrain-Source Voltage60Gate-Source Voltage-Continuous±20Drain Current-Continuous60Drain Current-Single Pluse240Total Dissipation @Tc=25°C60Max. Operating Junction Temperature-55~150				

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.75	°C/W



isc website: <u>www.iscsemi.com</u>

¹ *isc & iscsemi* is registered trademark



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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 1mA	60		V
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} = 10V; I _D = 1mA	1.2	2.6	V
R _{DS} (on)	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 30A V _{GS} = 4V; I _D = 30A		15 22	mΩ
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±16V;V _{DS} =0		±10	uA
I _{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 60V; V_{GS} = 0		1.0	uA
V _{SD}	Forward On-Voltage	I _S = 60A; V _{GS} = 0		1.5	V

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